## RENESAS

# NESG340034

NPN Silicon Germanium RF Transistor

R09DS0023EJ0200 Rev.2.00 Aug 18, 2011

### DESCRIPTION

The NESG340034 is an ideal choice for low noise, low distortion amplification.

### FEATURES

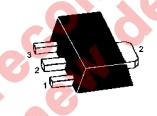
- NF = 0.65 dB TYP. @  $V_{CE}$  = 5 V,  $I_C$  = 15 mA, f = 1 GHz
- $P_{o(1 \text{ dB})} = 24 \text{ dBm TYP}$ . @  $V_{CE} = 5 \text{ V}$ ,  $I_{C (set)} = 40 \text{ mA}$ , f = 1 GHz
- $OIP_3 = 35.5 \text{ dBm TYP.}$  @  $V_{CE} = 5 \text{ V}$ ,  $I_{C \text{ (set)}} = 40 \text{ mA}$ , f = 1 GHz
- Maximum stable power gain: MSG =12.0 dB TYP. @  $V_{CE}$  = 5 V,  $I_C$  = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS3) :  $f_T = 10 \text{ GHz}$
- This product is improvement of ESD
- 3-pin power minimold (34 PKG)

### **APPLICATIONS**

• Suitable for up to 1 GHz applications. e.g. LNA (Low Noise Amplifier) or booster amplifier for Digital-TV.

### OUTLINE

RENESAS Package code: 34 (Package name: 3-pin power minimold (34 PKG))



Emitter
Collector
Base

Note: Marking is "ST"

### ORDERING INFORMATION

		The second se		
Part Number	Order Number	Package	Quantity	Supplying Form
NESG340034	NESG340034-A	3-pin power minimold	25 pcs (Non reel)	Magazine case
NESG340034-T1	NESG340034-T1-A	(34 PKG) (Pb-Free)	1 kpcs/reel	<ul><li>Embossed tape 12 mm wide</li><li>Pin 2 face the perforation side of the tape</li></ul>

**Remark** To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 25 pcs.

### CAUTION

Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25^{\circ}C$ )

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V <sub>CBO</sub>	5.5	V
Collector to Emitter Voltage (Base Short)	V <sub>CES</sub>	13	V
Collector to Emitter Voltage (Base Open)	V <sub>CEO</sub>	5.5	V
Base Current Note1	Ι <sub>Β</sub>	36	mA
Collector Current	Ι <sub>C</sub>	400	mA
Total Power Dissipation Note2	P <sub>tot</sub>	886	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	–65 to +150	°C

Notes: 1. Depend on the ESD protect device.

2. Mounted on 3.8 cm × 9.0 cm × 0.8 mm (t) glass epoxy PWB

### THERMAL RESISTANCE ( $T_A = +25^{\circ}C$ )

Parameter	Symbol	Ratings	Unit	
Thermal Resistance from Junction to Ambient Note	Rth <sub>j-a</sub>	141	°C/W	

Note: Mounted on 3.8 cm × 9.0 cm × 0.8 mm (t) glass epoxy PWB

## **RECOMMENDED OPERATING RANGE (T<sub>A</sub> = +25^{\circ}C)**

Parameter	Symbol	MIN.	TYP. MAX.	Unit
Collector Current	Ι <sub>C</sub>	-	40 –	mA
		e C	6 ° 6	



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### ELECTRICAL CHARACTERISTICS ( $T_A = +25^{\circ}C$ )

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I <sub>CBO</sub>	$V_{CB} = 5 V, I_E = 0$	-	-	100	nA
Emitter Cut-off Current	I <sub>EBO</sub>	$V_{EB} = 0.4 \text{ V}, I_{C} = 0$	-	_	100	nA
DC Current Gain	h <sub>FE</sub> <sup>Note1</sup>	$V_{CE}$ = 5 V, I <sub>C</sub> = 15 mA	200	320	500	1
RF Characteristics						
Gain Bandwidth Product	f <sub>T</sub>	$V_{CE}$ = 5 V, $I_C$ = 40 mA, f = 1 GHz	-	10.0	Ι	GHz
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	$V_{CE}$ = 5 V, $I_C$ = 40 mA, f = 1 GHz	8.5	10.5	Ι	dB
Noise Figure (1)	NF1	$V_{CE}$ = 5 V, I <sub>C</sub> = 15 mA, f = 1 GHz,	-	0.65	1.05	dB
		$Z_S = Z_{Sopt}, Z_L = 50 \Omega$				
Noise Figure (2)	NF2	$V_{CE}$ = 5 V, $I_C$ = 40 mA, f = 1 GHz,	-	0.7	-	dB
		$Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$				
Associated Gain (1)	G <sub>a</sub> 1	$V_{CE}$ = 5 V, $I_{C}$ = 15 mA, f = 1 GHz,	8.0	10.0	-	dB
		$Z_{S} = Z_{Sopt}, Z_{L} = 50 \Omega$				
Associated Gain (2)	G <sub>a</sub> 2	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 40 mA, f = 1 GHz,	-	11.0	-	dB
		$Z_{\rm S} = Z_{\rm Sopt}, Z_{\rm L} = Z_{\rm Lopt}$				
Reverse Transfer Capacitance	C <sub>re</sub> Note 2	$V_{CB} = 5 V, I_E = 0, f = 1 MHz$	-	1.1	1.3	pF
Maximum Stable Power Gain	MSG Note 3	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 40 mA, f = 1 GHz	10.0	12.0	-	dB
Gain 1 dB Compression Output	P <sub>O (1 dB)</sub>	V <sub>CE</sub> = 5 V, I <sub>C (set)</sub> = 40 mA, f = 1 GHz,		24.0	-	dBm
Power		$Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$				
Output 3rd Order Intercept	OIP <sub>3</sub>	$V_{CE}$ = 5 V, $I_{C (set)}$ = 40 mA, f = 1 GHz,	-	35.5	-	dBm
Point		⊿f = 1 MHz, Z <sub>S</sub> = Z <sub>Sopt</sub> , Z <sub>L</sub> = Z <sub>Lopt</sub>				

Notes: 1. Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

o\_\_\_\_ 2. Collector to base capacitance when the emitter grounded.

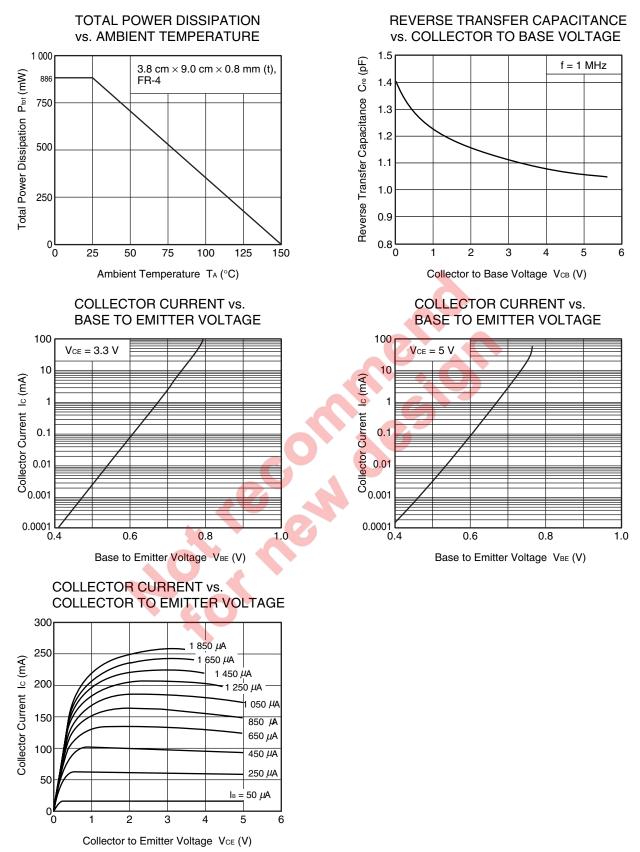
3. MSG = 
$$\frac{S_{21}}{S_{12}}$$

### **h**FE CLASSIFICATION

Rank	FB
Marking	ST
$h_{\text{FE}}$ Value	200 to 500

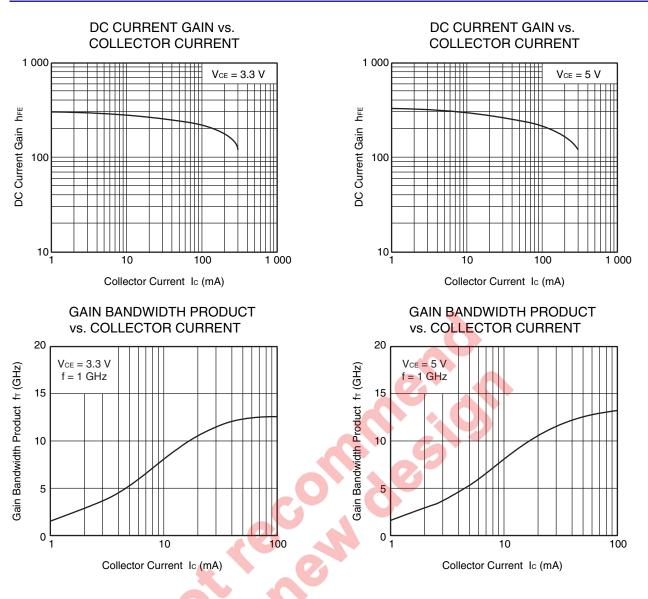


### TYPICAL CHARACTERISTICS ( $T_A = +25^{\circ}C$ , unless otherwise specified)



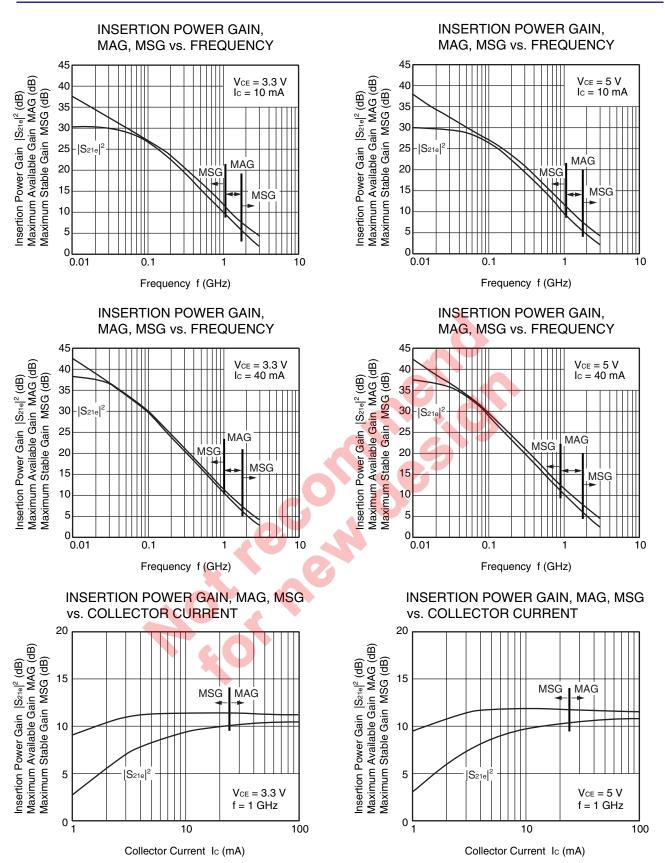


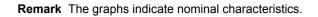




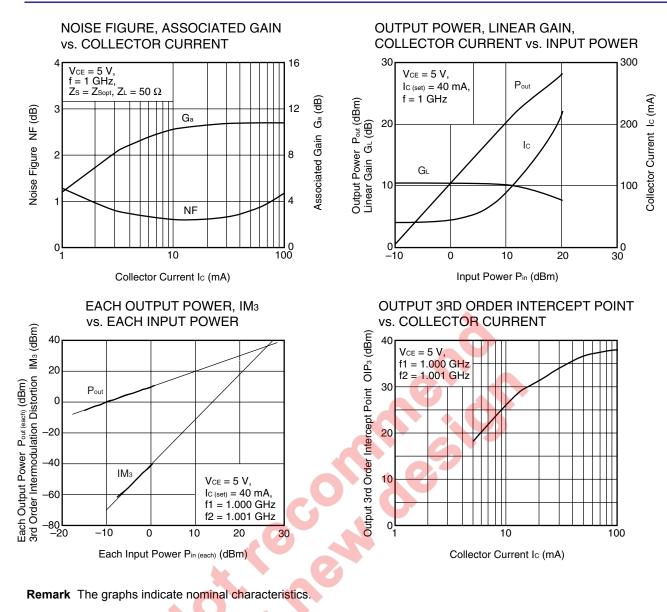
Remark The graphs indicate nominal characteristics.













### S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

Click here to download S-parameters.

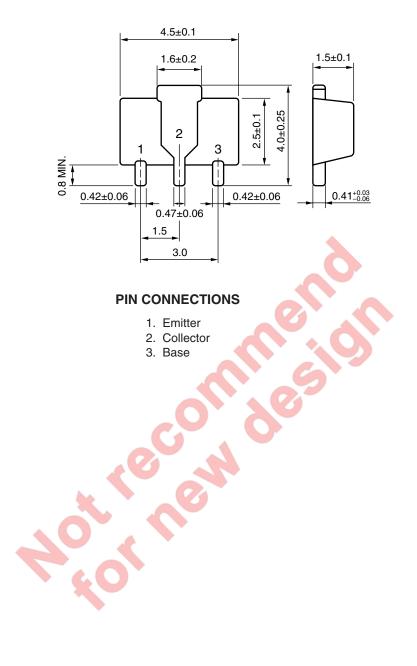
[RF and Microwave] → [Device Parameters] URL http://www2.renesas.com/microwave/en/download.html





### PACKAGE DIMENSIONS

#### 3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)





**Revision History** 

NESG340034 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Jun 27, 2011	-	First edition issued	
2.00	Aug 18, 2011	p.3	ELECTRICAL CHARACTERISTICS	
			DC Current Gain 400 $\rightarrow$ 500 (MAX.)	



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